TOSHIBA Photocoupler GaAs IRed & Photo-Transistor

# **TLP631,TLP632**

**Programmable Controllers** AC / DC-Input Module Solid State Relay

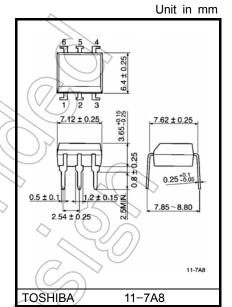
The TOSHIBA TLP631 and TLP632 consist of a photo-transistor optically coupled to a gallium arsenide infrared emitting diode in a six lead plastic DIP.

TLP632 is no-base internal connection for high-EMI environments.

- Collector-emitter voltage: 55 V (min.)
- Current transfer ratio: 50% (min.)

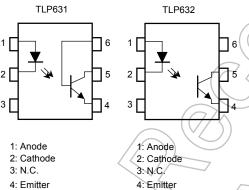
Rank GB: 100% (min.)

- Isolation voltage:  $5000V_{rms}$  (min.)
- UL recognized: UL1577, file no. E67349



Weight: 0.4 g (typ.)

#### Pin Configurations (top view)



- 4: Emitter
- 5: Collector
- 6: Base
- 5: Collector

6: N.C



#### Absolute Maximum Ratings (Ta = 25°C)

	Characteristic	Symbol	Rating	Unit
Forward current		IF	60	mA
	Forward current derating (Ta ≥ 39°C)		-0.7	mA / °C
딤	Peak forward current (100µs pulse, 100pps)	I <sub>FP</sub>	1	A
	Reverse voltage	V <sub>R</sub>	5	V
	Junction temperature	Tj	125	°C
	Collector-emitter voltage	V <sub>CEO</sub>	55	N/\
	Collector-base voltage (TLP631)	V <sub>CBO</sub>	80	((y))
	Emitter-collector voltage	V <sub>ECO</sub>	7	V
Detector	Emitter-base voltage (TLP631)	V <sub>EBO</sub>	7	) v
Dete	Collector current	Ic	50	mA
	Power dissipation	PC	150	mW
	Power dissipation derating (Ta ≥ 25°C)	ΔP <sub>C</sub> / °C	(7)≠1.5	mW / °C
	Junction temperature	T <sub>j</sub>	125	
Stor	age temperature range	T <sub>stg</sub>	_55~125	°C
Оре	rating temperature range	Topr	<b>−55~100</b>	(°C)
Lea	d soldering temperature (10s)	T <sub>sol</sub>	260	,c)
Total package power dissipation		PT	250	mW
Tota	al package power dissipation derating (Ta≥ 25°C)	ΔΡ <sub>Τ</sub> / °C	-2.5	mW / °C
Isola	ation voltage (AC, 1 min., R.H. ≤ 60%)	BVS	5000	V <sub>rms</sub>

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

### **Recommended Operating Conditions**

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Supply voltage	V <sub>CC</sub>	_	5	24	V
Forward current	lF	_	16	25	mA
Collector current	√ lc	_	1	10	mA
Operating temperature	T <sub>opr</sub>	-25	_	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

## Individual Electrical Characteristics (Ta = 25°C)

	Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
	Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 10 mA	1.0	1.15	1.3	V
ED	Reverse current	I <sub>R</sub>	V <sub>R</sub> = 5V	_	_	10	μΑ
	Capacitance	C <sub>T</sub>	V = 0, f = 1 MHz	1	30		pF
	Collector–emitter breakdown voltage	V <sub>(BR)</sub> CEO	I <sub>C</sub> = 0.5 mA	55	7	_	V
Detector	Emitter–collector breakdown voltage	V <sub>(BR)</sub> ECO	I <sub>E</sub> = 0.1 mA	7	) –	1	٧
	Collector–base breakdown voltage (TLP631)	V <sub>(BR)</sub> CBO	I <sub>C</sub> = 0.1 mA	80	1	1	٧
	Emitter-base breakdown voltage (TLP631)	V <sub>(BR)</sub> EBO	I <sub>E</sub> = 0.1 mA	7	)	1	٧
	Collector dark current	1	V <sub>CE</sub> = 24 V	_	10	100	nA
	Conector wark current	ICEO	V <sub>CE</sub> = 24 V, Ta = 85°C	- (	2	50	μA
	Capacitance collector to emitter	C <sub>CE</sub>	V = 0, f = 1 MHz	-((	10	<u> </u>	pF

# Coupled Electrical Characteristics (Ta = 25°C)

		Al ()	701			
Characteristic	Symbol	Test Condition	MIn.	Тур.	Max.	Unit
Current transfer ratio	I <sub>C</sub> / I <sub>F</sub> = 5 mA, V <sub>CE</sub> = 5 V Rank GB		) 50	_	600	%
	Ic / IF Rank GB	Rank GB	100	_	600	70
Saturated CTR	I <sub>F</sub> = 1 mA, V <sub>CE</sub> = 0.4 V Rank GB	ı	60	ı	%	
	IC (IF (sat)	Rank GB	30	_	ı	70
Collector–emitter saturation voltage	V <sub>CE</sub> (sat)	I <sub>C</sub> = 2.4 mA, I <sub>F</sub> = 8 mA	1	_	0.4	V

## Isolation Characteristics (Ta = 25°C)

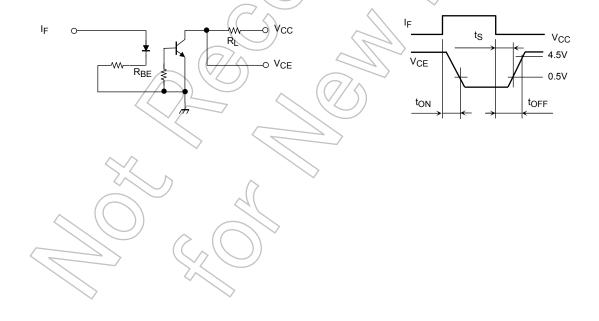
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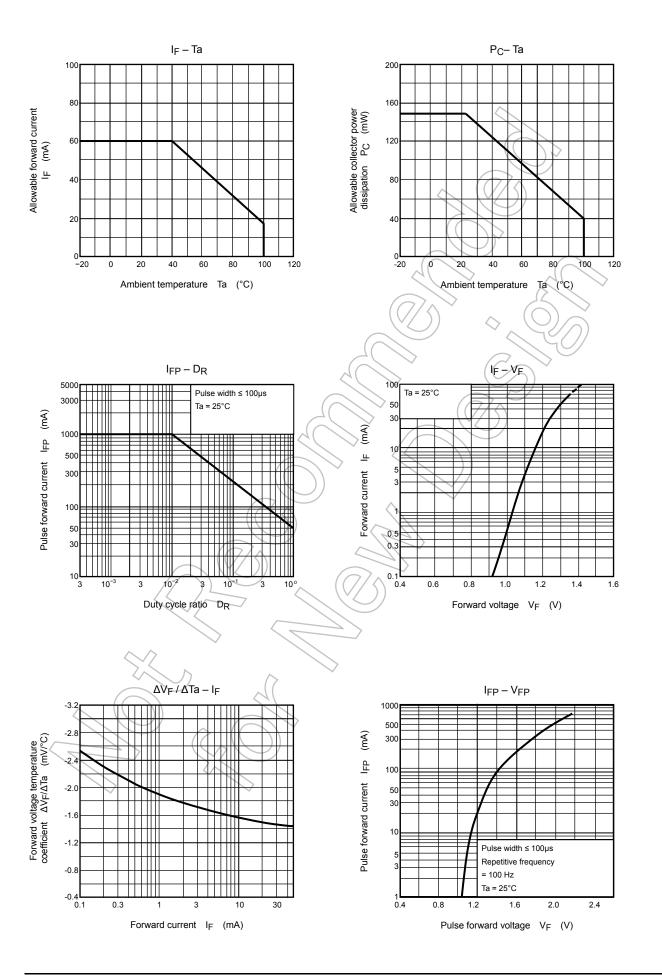
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Capacitance (input to output)	Cs	V <sub>S</sub> = 0, f = 1 MHz	_	8.0	_	pF
Isolation resistance	R <sub>S</sub>	V <sub>S</sub> = 500 V, R.H. ≤ 60%	5×10 <sup>10</sup>	10 <sup>14</sup>	_	Ω
	BVS	AC, 1 minute	5000	_	_	V
Isolation voltage		AC, 1 second, in oil		10000	_	V <sub>rms</sub>
		DC, 1 minute, in oil	1	10000	_	V <sub>dc</sub>

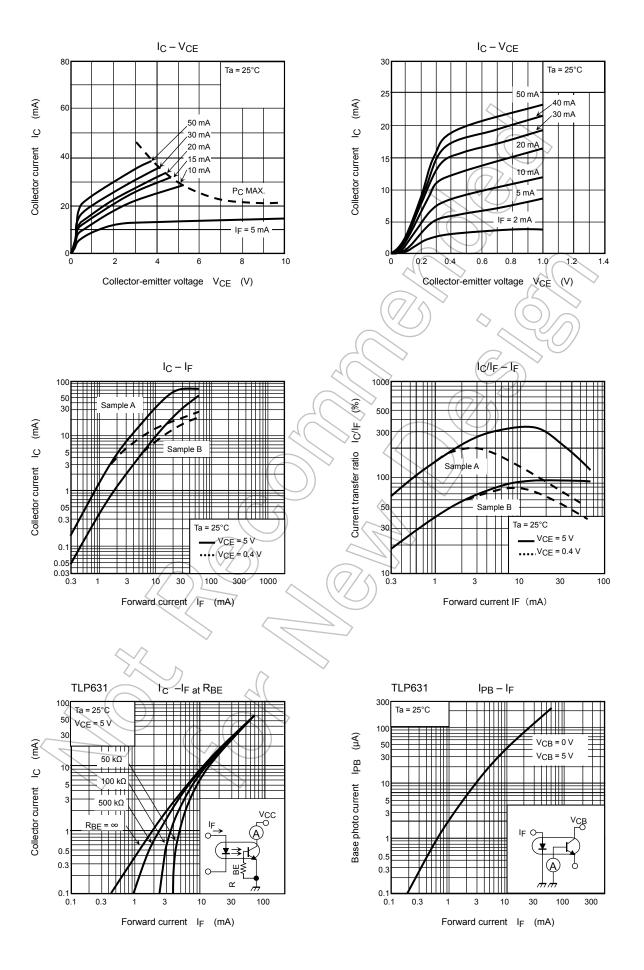
### **Switching Characteristics (Ta = 25°C)**

Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Rise time	t <sub>r</sub>		_	2	_	
Fall time	t <sub>f</sub>	$V_{CC} = 10 \text{ V, } I_{C} = 2 \text{ mA}$ $R_{L} = 100\Omega$		3	$\rightarrow$	ше
Turn-on time	t <sub>on</sub>	$R_L = 100\Omega$	-6	3	> -	μs
Turn-off time	t <sub>off</sub>		~_(	3	) —	
Turn-on time	t <sub>ON</sub>	$R_L = 1.9 \text{ k}\Omega$ (Fig.1)		2/	_	
Storage time	t <sub>S</sub>	R <sub>BE</sub> = OPEN V <sub>CC</sub> = 5 V, I <sub>F</sub> = 16 mA		15	_	μs
Turn-off time	tOFF	VCC = 5 V, IF = 16 MA	( <del>-]</del> ]	25	_	
Turn-on time	ton	$R_L = 1.9 \text{ k}\Omega$ (Fig. 1)	\ -	2	_	
Storage time	t <sub>s</sub>	$R_{BF} = 220 \text{ k}\Omega(\text{TLP631})$	/ _	12	_	μs
Turn-off time	t <sub>OFF</sub>	$V_{CC} = 5 \text{ V, I}_F = 16 \text{ mA}$	1	20		

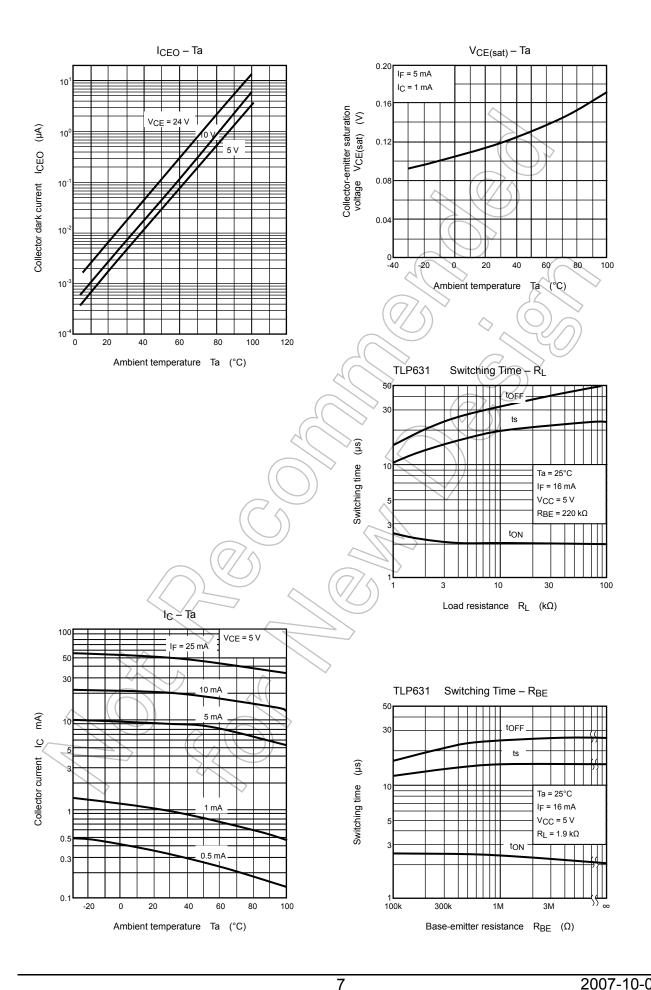
Fig. 1 Switching time test circuit







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